Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

Between 0.240 inches and 0.260 inches

Terminal Length:

Between 0.500 inches and 0.750 inches

Overall Diameter:

Between 0.335 inches and 0.370 inches

Function For Which Designed:

Reverse blocking

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Anode

Mounting Method:

Terminal **Terminal Circle Diameter:**

0.200 inches

Features Provided:

Quality assurance level tx and burn in and hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 reverse voltage, peak and 150.0 nonrepetitive peak reverse voltage, peak total value

Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pnpn

Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

3 uninsulated wire lead

Specification Data:

81349-mil-s-19500/276 government specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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